



2SB885/2SD1195

Driver Applications

Applications

- Motor drivers, printer hammer drivers, relay drivers, voltage regulator control.

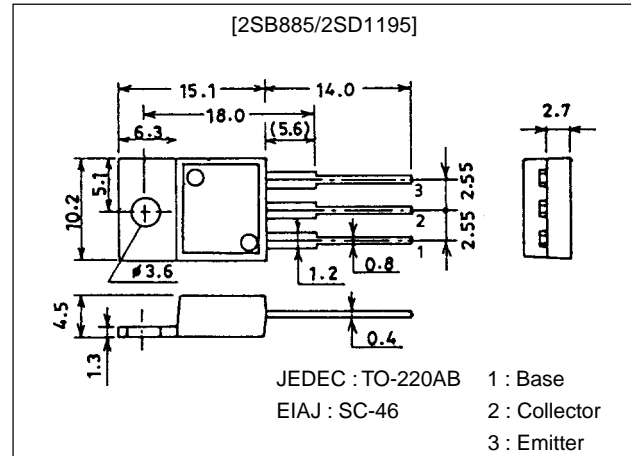
Features

- High DC current gain.
- High current capacity and wide ASO.
- Low saturation voltage.

Package Dimensions

unit:mm

2010C



() : 2SB885

Specifications

Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CB0}		(-)110	V
Collector-to-Emitter Voltage	V_{CEO}		(-)100	V
Emitter-to-Base Voltage	V_{EBO}		(-)6	V
Collector Current	I_C		(-)5	A
Collector Current (Pulse)	I_{CP}		(-)8	A
Collector Dissipation	P_C		1.75	W
		$T_c=25^\circ\text{C}$	35	W
Junction Temperature	T_j		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=(-)80\text{V}, I_E=0$			(-)0.1	mA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=(-)5\text{V}, I_C=0$			(-)3.0	mA
DC Current Gain	h_{FE}	$V_{CE}=(-)3\text{V}, I_C=(-)2.5\text{A}$	1500	4000		
Gain-Bandwidth Product	f_T	$V_{CE}=(-)5\text{V}, I_C=(-)2.5\text{A}$		20		MHz
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)2.5\text{A}, I_B=(-)5\text{mA}$		0.9	(-)1.5	V
				(-1.0)		V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)2.5\text{A}, I_B=(-)5\text{mA}$			(-)2.0	V

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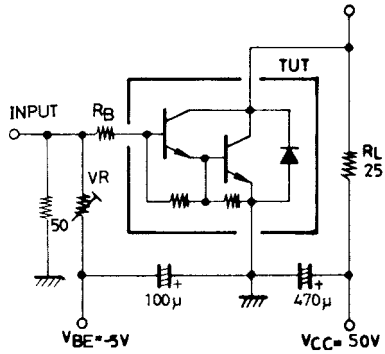
SANYO Electric Co., Ltd. Semiconductor Business Headquarters

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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = (-)5mA, I_E = 0$	(-)110			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = (-)50mA, R_{BE} = \infty$	(-)100			V
Turn-ON Time	t_{on}	See specified Test Circuit		(0.7)		μs
				0.6		μs
Storage Time	t_{stg}	See specified Test Circuit		(1.3)		μs
				4.8		μs
Fall Time	t_f	See specified Test Circuit		(1.5)		μs
				1.6		μs

Switching Time Test Circuit



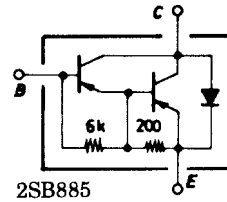
Unit (resistance : Ω , capacitance : F)

(For PNP, the polarity is reversed.)

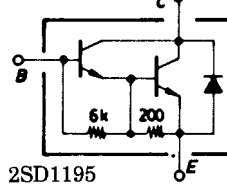
PW = 50 μs , Duty Cycle \leq 1%

500I_{B1} = -500I_{B2} = I_C = 2A

Electrical Connection

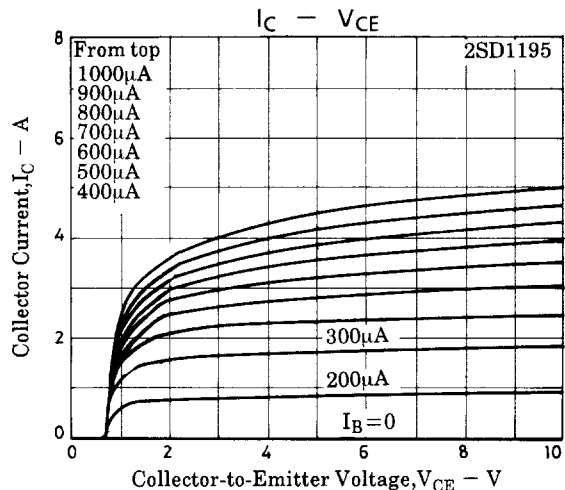
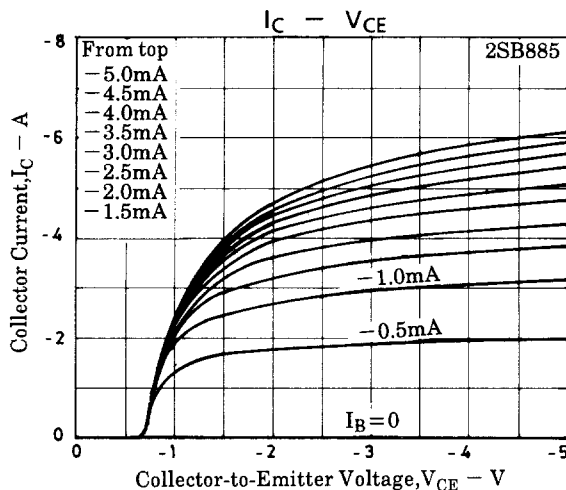
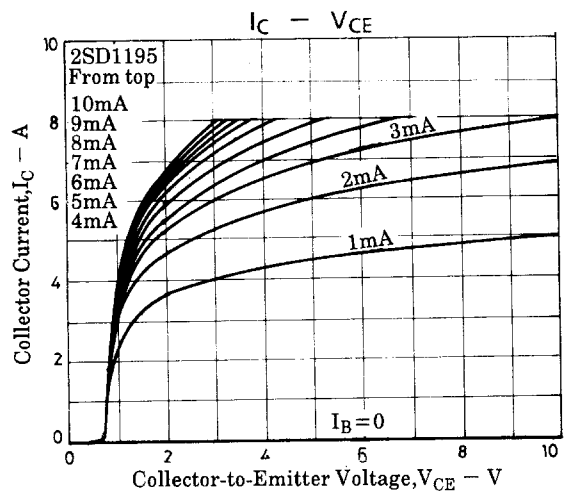
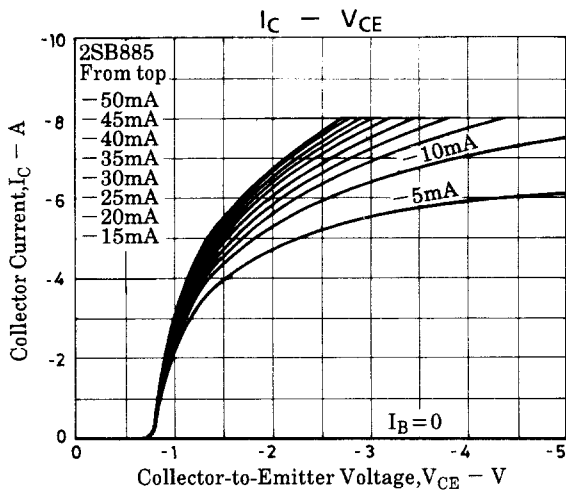


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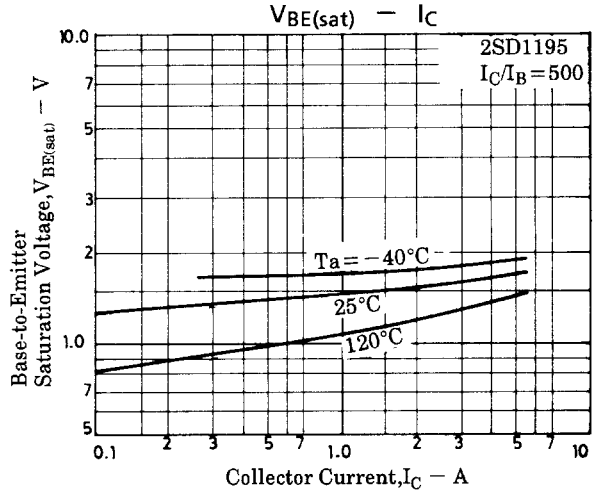
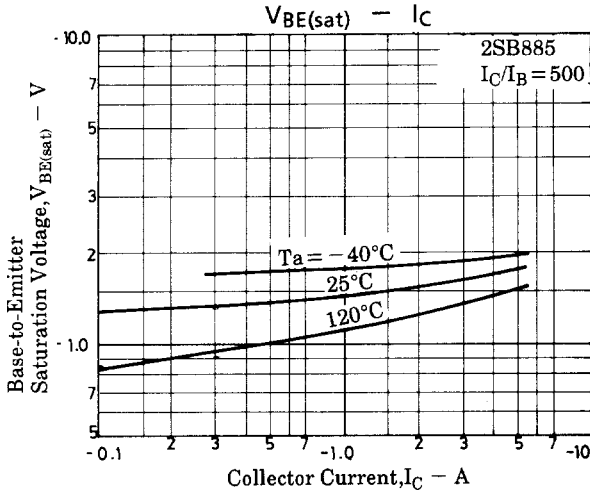
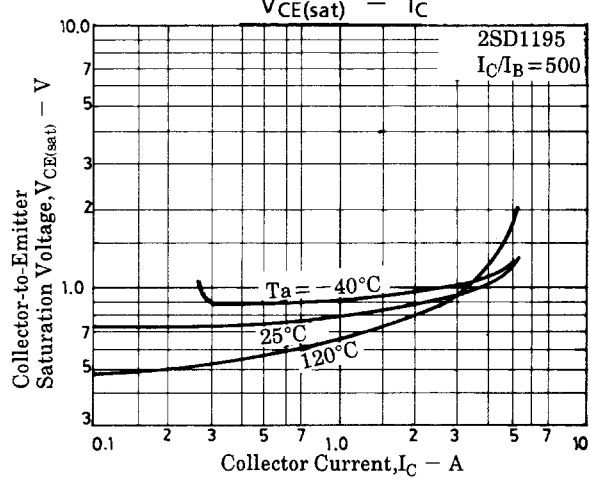
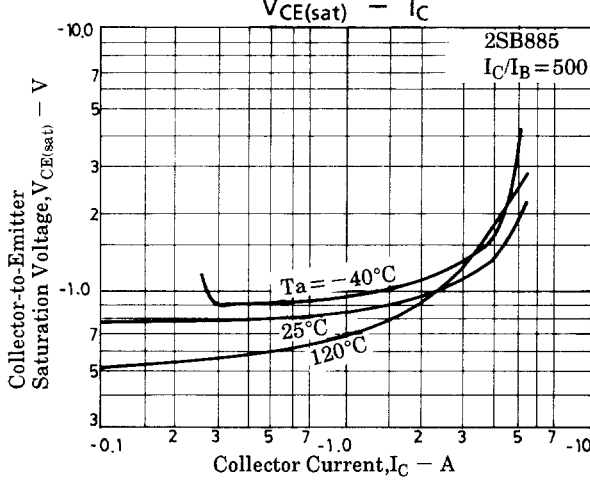
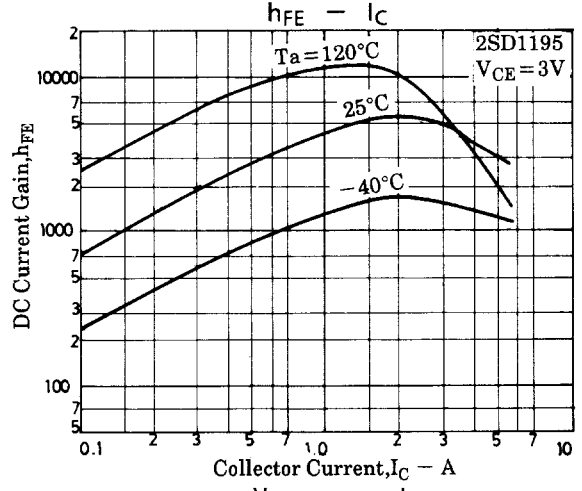
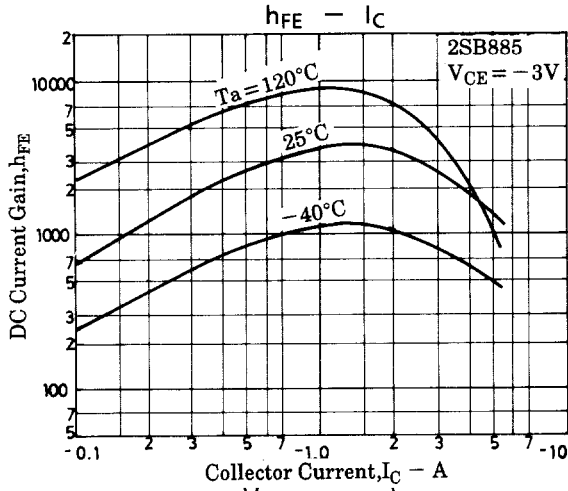
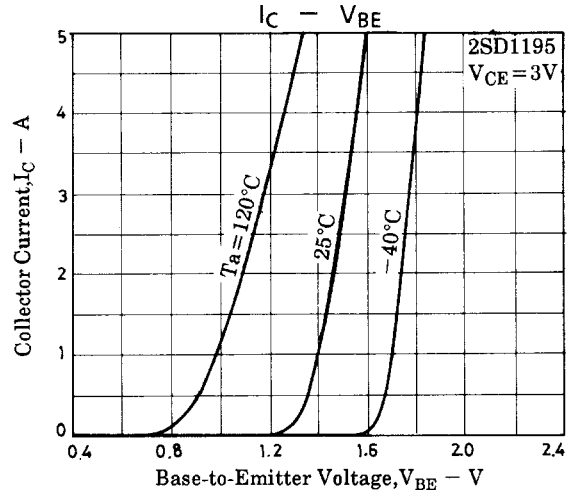
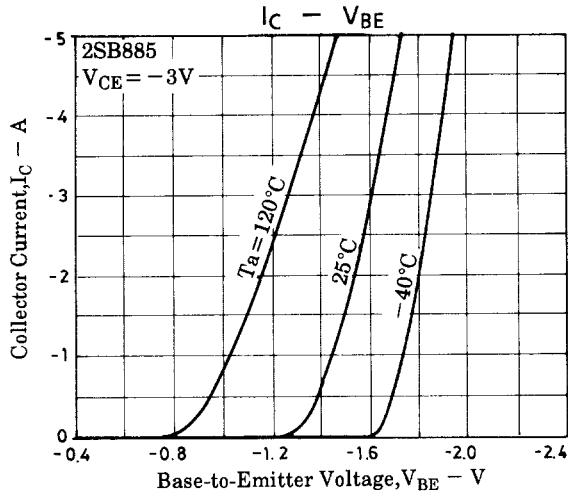


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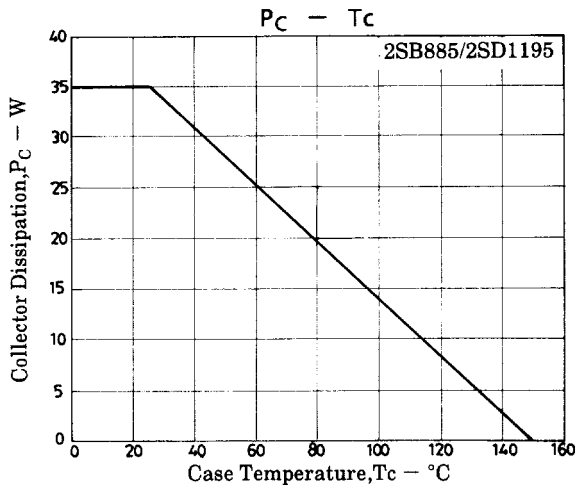
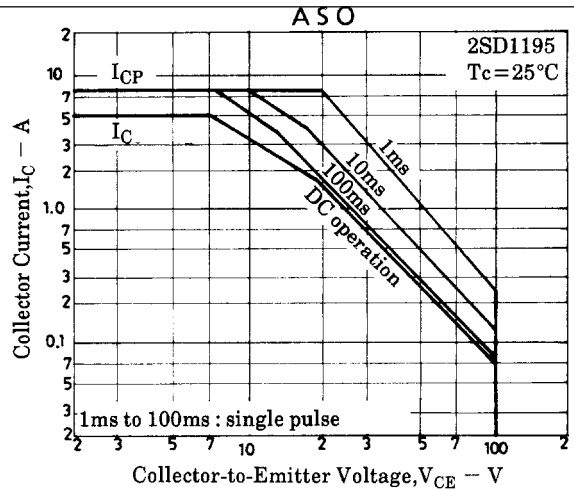
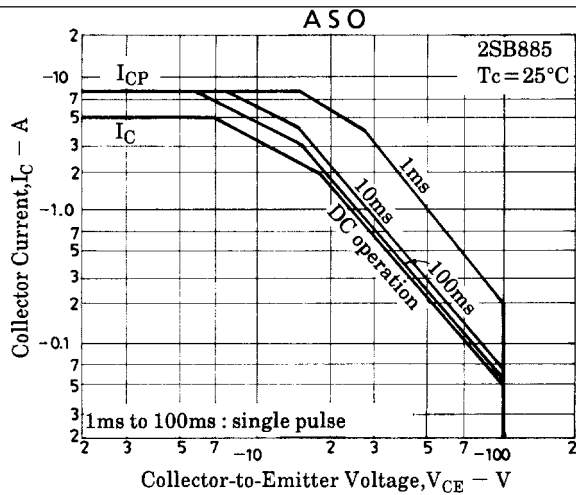
Unit (resistance : Ω)



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